



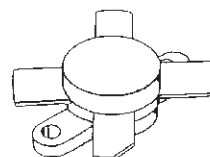
SD2921

RF & MICROWAVE TRANSISTORS HF/VHF/UHF N-CHANNEL MOSFETs

- GOLD METALLIZATION
- EXCELLENT THERMAL STABILITY
- COMMON SOURCE CONFIGURATION
- POUT = 150W MIN. WITH 12.5 dB gain @175 MHz

DESCRIPTION

The SD2921 is a gold metallized N-Channel MOS field-effect RF power transistor. The SD2921 is intended for use in 50V dc large signal applications up to 200 MHz

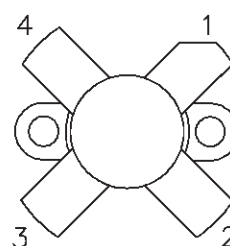


.500 4LFL (M174)
epoxy sealed

ORDER CODE
SD2921

BRANDING
SD2921

PIN CONNECTION



1. Drain 3. Gate
2. Source 4. Source

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^{\circ}C$)

Symbol	Parameter	Value	Unit
$V_{(BR)DSS}$	Drain Source Voltage	125	V
V_{DGR}	Drain-Gate Voltage ($R_{GS} = 1M\Omega$)	125	V
V_{GS}	Gate-Source Voltage	± 40	V
I_D	Drain Current	16	A
P_{DISS}	Power Dissipation	292	W
T_j	Max. Operating Junction Temperature	200	$^{\circ}C$
T_{STG}	Storage Temperature	-65 to 150	$^{\circ}C$

THERMAL DATA

$R_{th(j-c)}$	Junction-Case Thermal Resistance	0.6	$^{\circ}C/W$
$R_{th(c-s)}$	Case-Heatsink Thermal Resistance *	0.2	$^{\circ}C/W$

* Determined using a flat aluminum or copper heatsink with thermal compound applied (Dow Corning 340 or equivalent).

ELECTRICAL SPECIFICATION (T_{case} = 25 °C)

STATIC

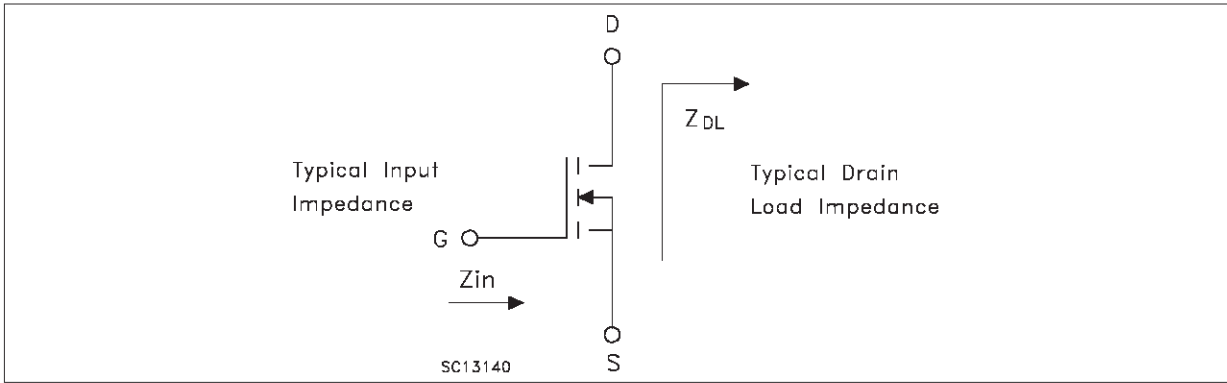
Symbol	Parameter			Min.	Typ.	Max.	Unit
V _{(BR)DSS}	V _{GS} = 0V	I _{DS} = 100 mA		125			V
I _{DSS}	V _{GS} = 0V	V _{DS} = 50 V				5	mA
I _{GSS}	V _{GS} = 20V	V _{DS} = 0 V				5	μA
V _{GS(Q)}	V _{DS} = 10V	I _D = 250 mA		1.0		5.0	V
V _{DS(ON)}	V _{GS} = 10V	I _D = 10 A				3.0	V
G _{FS}	V _{DS} = 10V	I _D = 5 A		4			mho
C _{ISS}	V _{GS} = 0V	V _{DS} = 50 V	f = 1 MHz		411		pF
C _{OSS}	V _{GS} = 0V	V _{DS} = 50 V	f = 1 MHz		198		pF
C _{RSS}	V _{GS} = 0V	V _{DS} = 50 V	f = 1 MHz		27		pF

DYNAMIC

Symbol	Parameter			Min.	Typ.	Max.	Unit
P _{OUT}	f = 175 MHz	V _{DD} = 50 V	I _{DQ} = 250 mA	150			W
G _{PS}	f = 175 MHz	V _{DD} = 50 V	P _{out} = 150 W	12.5	14		dB
η _D	f = 175 MHz	V _{DD} = 50 V	P _{out} = 150 W	55	65		%
Load Mismatch	f = 175 MHz	V _{DD} = 50 V	P _{out} = 150 W	10:1			VSWR

REF. 1021304K

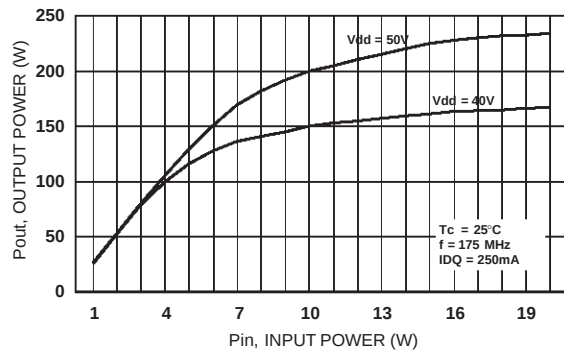
IMPEDANCE DATA



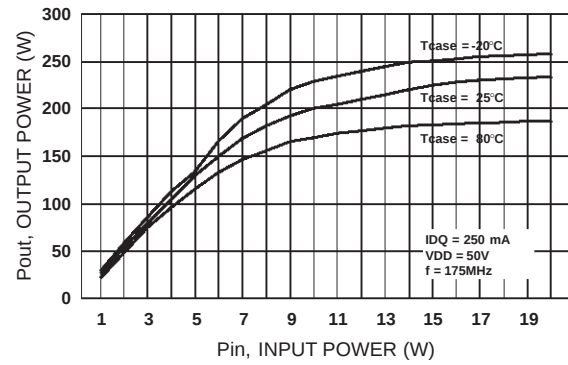
FREQ.	Z _{IN} (Ω)	Z _{DL} (Ω)
30 MHz	1.7 - j 5.7	6.8 + j 0.9
175 MHz	1.2 - j 2.0	2.0 + j 2.4

TYPICAL PERFORMANCE

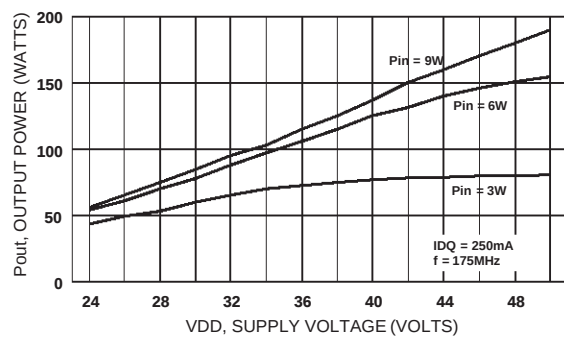
Output Power vs Input Power



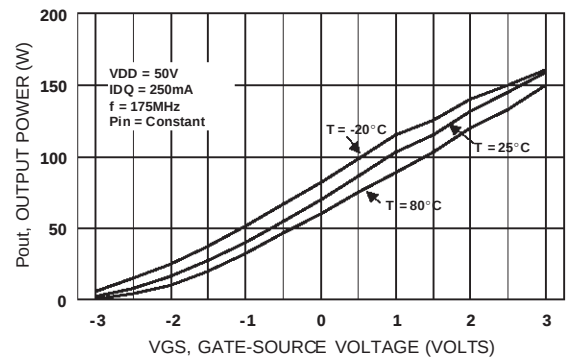
Output Power vs Input Power



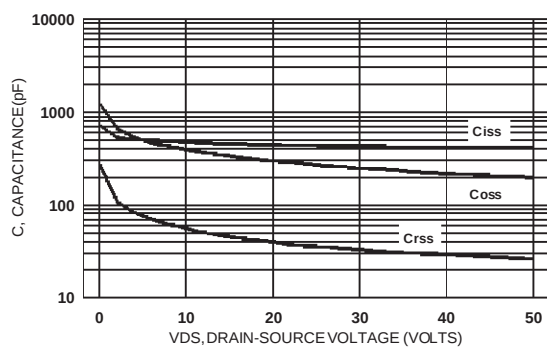
Output Power vs Supply Voltage



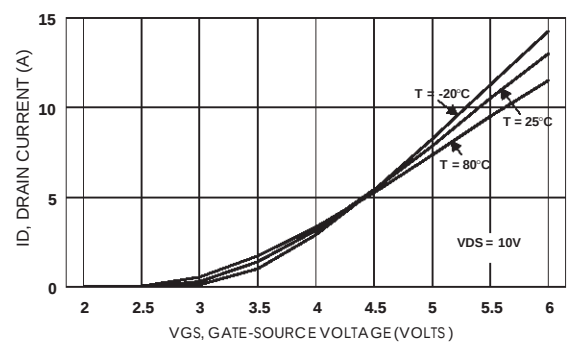
Output Power vs Gate Voltage



Capacitance vs Drain-Source Voltage

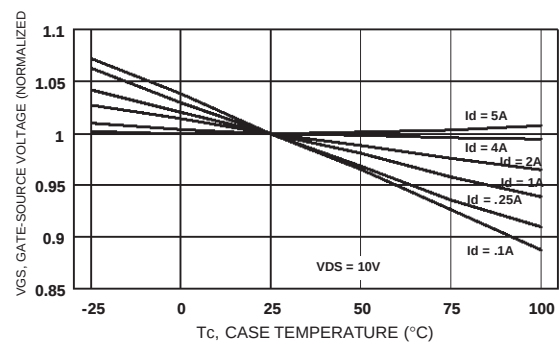


Drain Current vs Gate Voltage

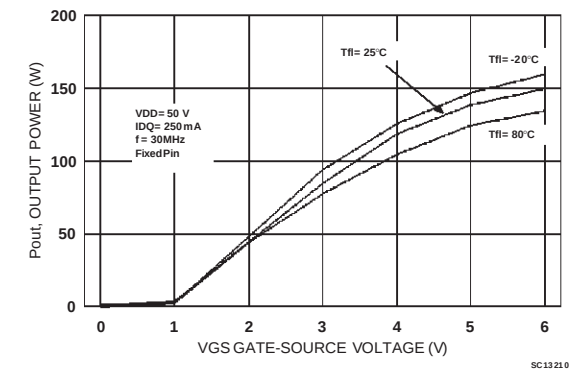


TYPICAL PERFORMANCE

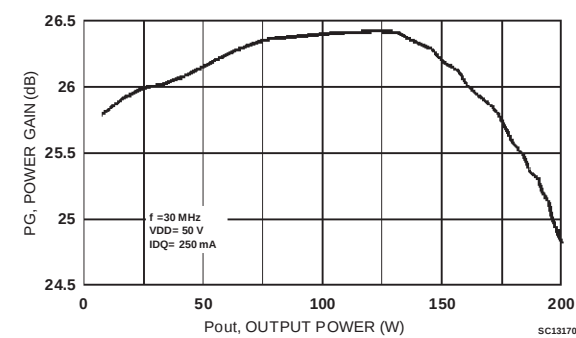
Gate-Source Voltages vs Case Temperature



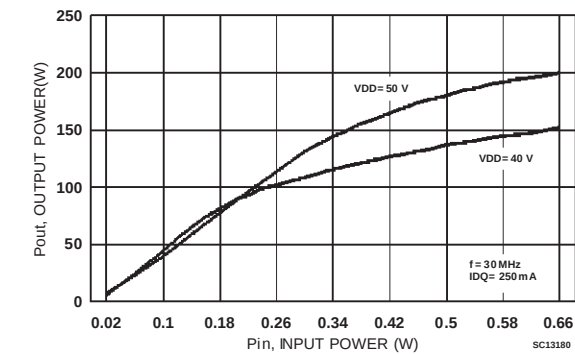
Output Power vs Gate Voltage



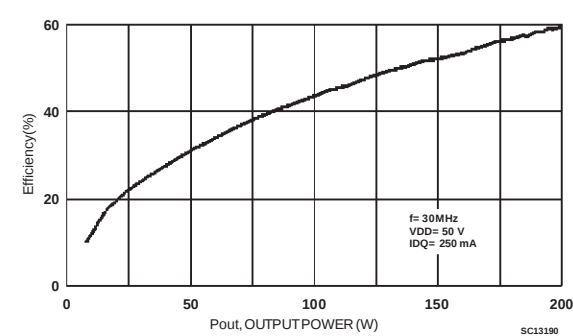
Power Gain vs Output Power



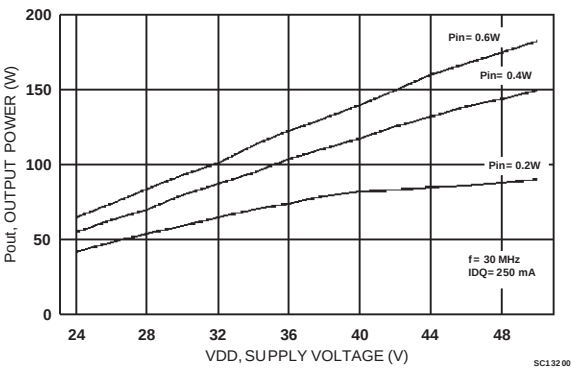
Output Power vs Input Power



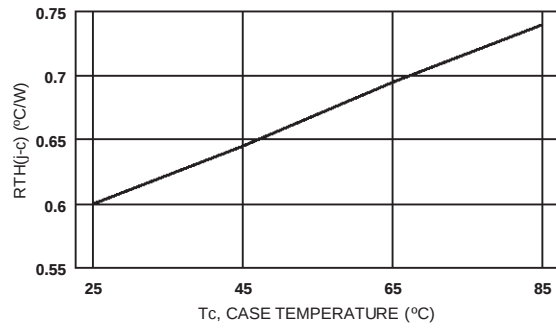
Efficiency vs Output Power



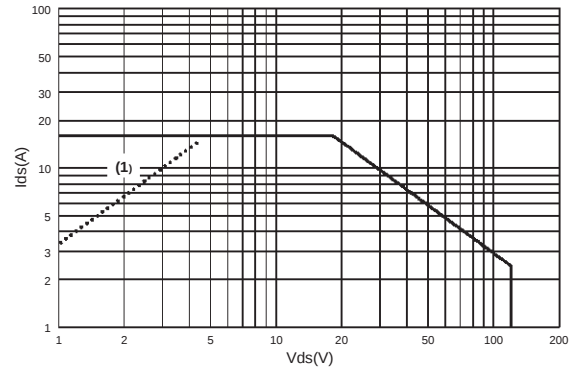
Output Power vs Voltage Supply



Maximum Thermal Resistance vs Case Temperature

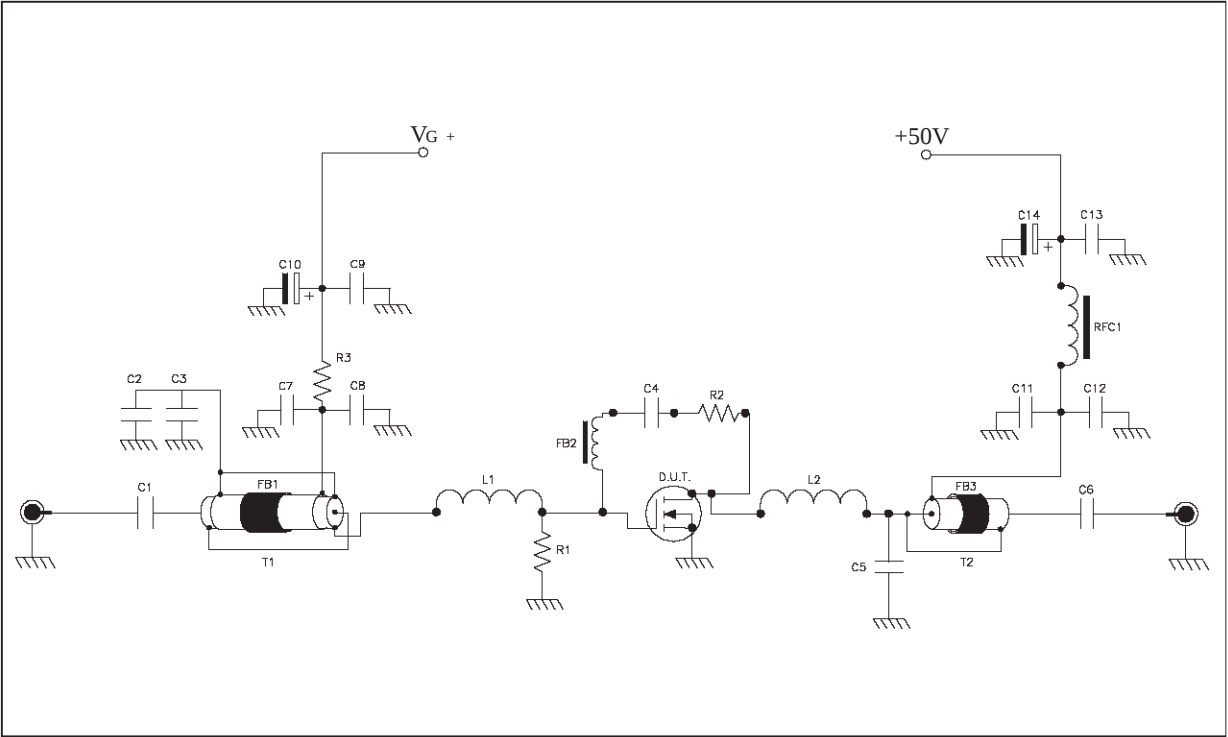


DC Safe Operating Area



(1) Current in this area may be limited by $R_{DS(on)}$

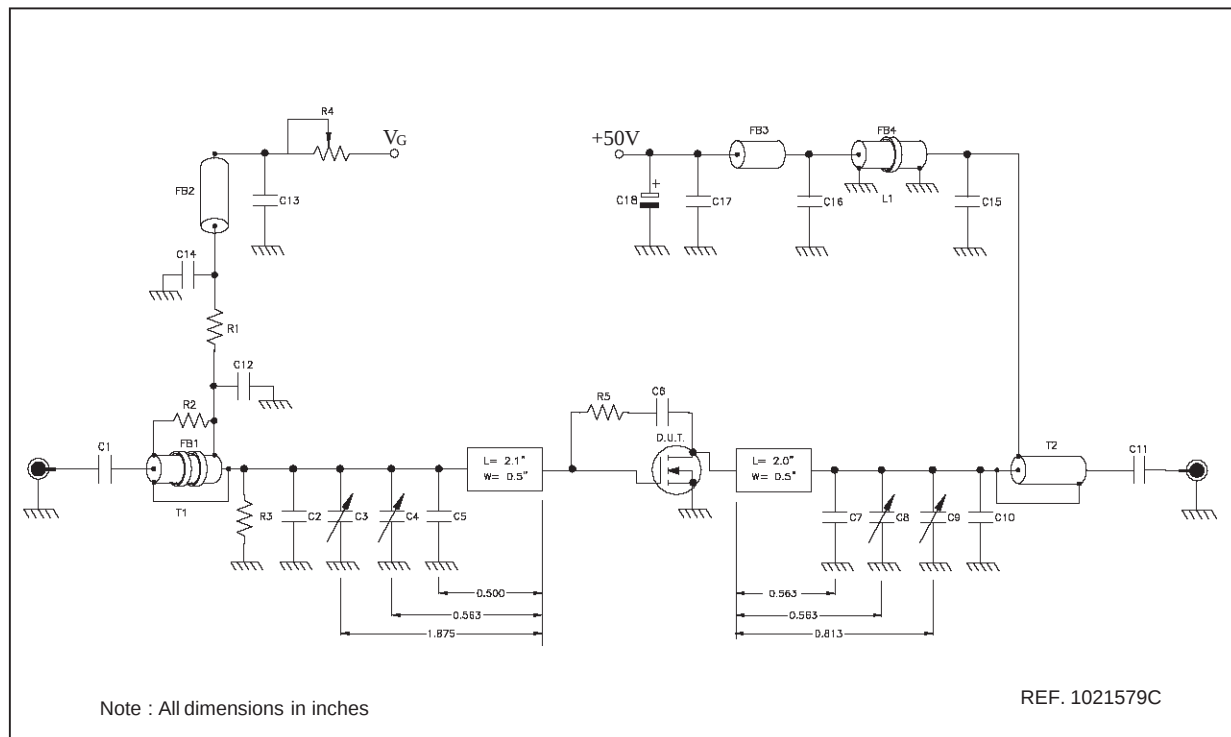
30 MHz Test Circuit Schematic (Engineering Test Circuit)



30 MHz Test Circuit Component Part List

T1	9:1 Transformer, 25 ohm Flexible Coax with extra shield .090 OD 15" Long		
T2	1:4 Transformer, 50 ohm Flexible Coax .225 OD 15" Long		
FB1	Toroid, 1.7" OD .30" ID 220u 4 Turns		
FB2	Surface Mount EMI Shield Bead		
FB3	Toroid, 1.7" OD .300" ID 220u 3 Turns		
RFC1	Toroid, 0.5" OD 0.30" ID, 125u 4 turns 12 awg wire		
PCB	0.062" Woven Fiberglass, 1 oz. Copper, 2 Sides, er = 2.55		
C1, C4, C6, C7, C8,	0.01 uF ATC Chip Cap	C5	470 pF ATC Chip Cap
C9, C11, C12, C13	0.01 uF ATC Chip Cap	C10	10 uF 63V Electrolytic Capacitor
C2, C3	750 pF ATC Chip Cap	C14	100 uF 63V Electrolytic Capacitor
R1, R3	1K ohm 1W Chip Resistor	R2	680 ohm 3W Wirewound Resistor

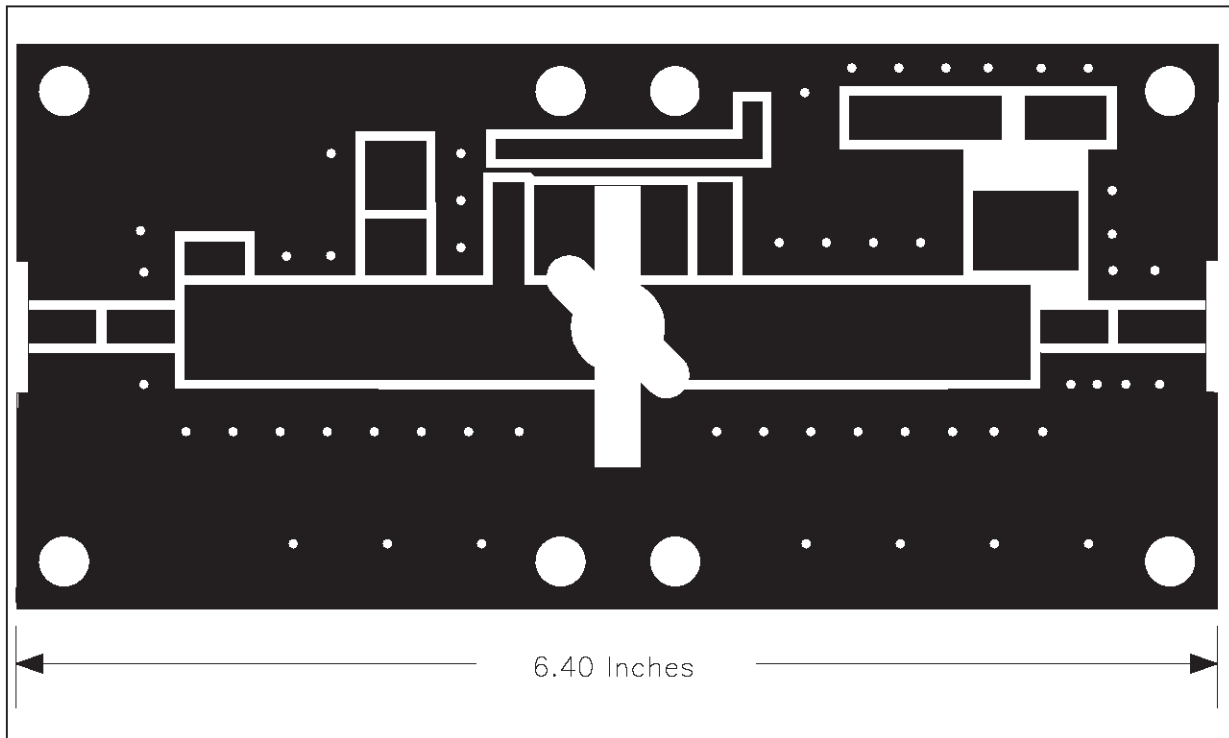
175 MHz Test Circuit Schematic (Production Test Circuit)



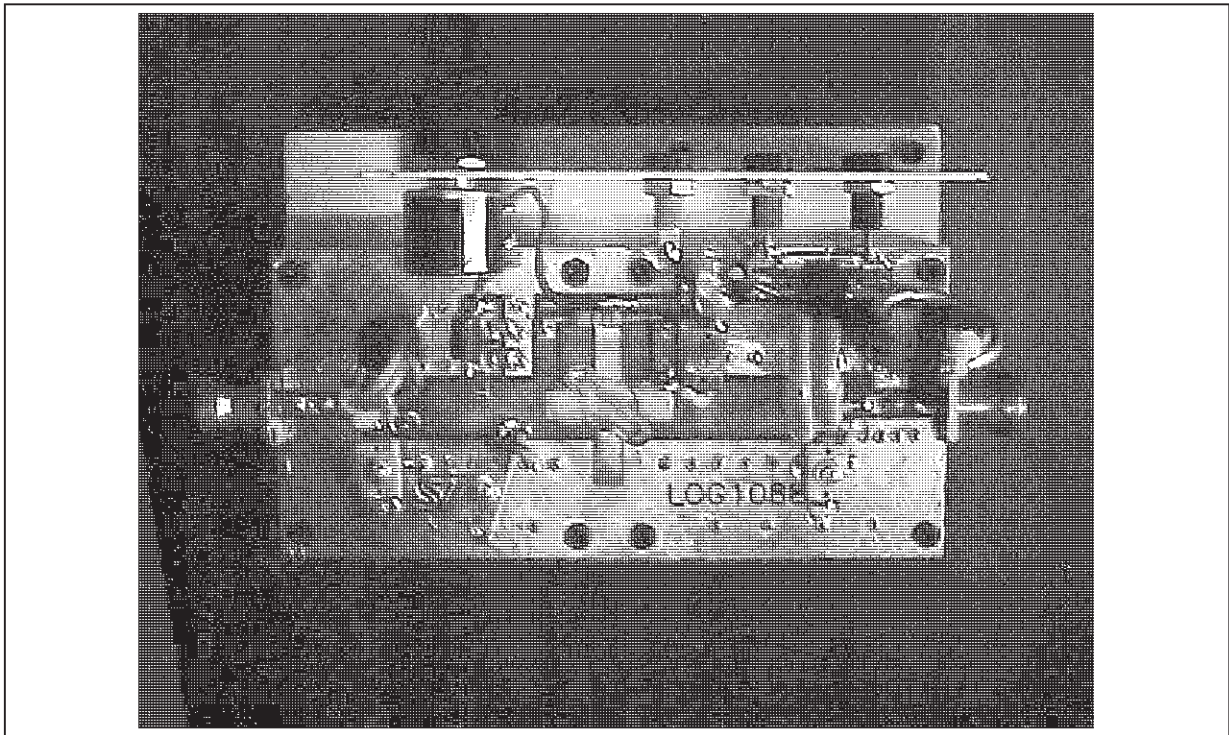
175 MHz Test Circuit Component Part List

T1	4:1 Transformer, 25 ohm Flexible Coax .090 OD 6 " Long		
T2	1:4 Transformer, 25 ohm Semi-Rigid Coax .141 OD 6 " Long		
FB1	Toroid X2, 0.5" OD .312" ID 850u 2 Turns		
FB2, FB3	VK200		
FB4	Shield Bead, 1" OD 0.5" ID 850u 3 Turns		
L1	1/4Wave Choke, 50 ohm Semi-Rigid Coax .141 OD 12 " Long		
PCB	0.062" Woven Fiberglass, 1 oz. Copper, 2 Sides, er = 2.55		
R1, R3	470 ohm 1W Chip Resistor	R4	20K ohm 10 Turn Potentiometer
R2	360 ohm 1/2W Resistor	R5	560 ohm 1W Resistor
C1, C11	470 pF ATC Chip Cap	C7	30 pF ATC Chip Cap
C2	43 pF ATC Chip Cap	C10	91 pF ATC Chip Cap
C3, C8, C9	Arco 404, 12-65 pF	C12, C15	1200 pF ATC Chip Cap
C4	Arco 423, 16-100 pF	C13, C14	0.01 uF / 500V Chip Cap
C5	120 pF ATC Chip Cap	C16, C17	0.01 uF / 500V Chip Cap
C6	0.01 uF ATC Chip Cap	C18	10 uF 63V Electrolytic Capacitor

175 MHz Test Circuit Photomaster

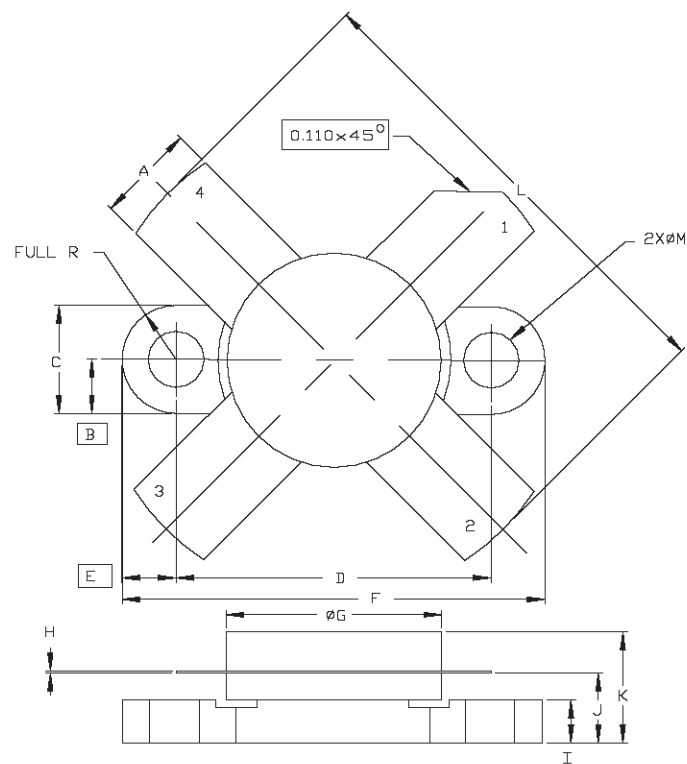


175 MHz Test Circuit



M174 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	5.56		5.84	0.219		0.230
B		3.18			0.125	
C	6.22		6.48	0.245		0.255
D	18.28		18.54	0.720		0.730
E		3.18			0.125	
F	24.64		24.89	0.970		0.980
G	12.57		12.83	0.495		0.505
H	0.08		0.18	0.003		0.007
I	2.11		3.00	0.083		0.118
J	3.81		4.45	0.150		0.175
K			7.11			0.280
L	25.53		26.67	1.005		1.050
M	3.05		3.30	0.120		0.130



1011000D

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